74AUP1G04-Q100

Low-power inverter

Rev. 5 — 20 September 2024

Product data sheet

1. General description

The 74AUP1G04-Q100 is a single inverter.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times across the entire VCC range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial Power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 0.8 V to 3.6 V
- · CMOS low power dissipation
- · High noise immunity
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V



3. Ordering information

Table 1. Ordering information

Type number	Package						
	Temperature range	Name	Description	Version			
74AUP1G04GV-Q100	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753			
74AUP1G04GW-Q100	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1			
74AUP1G04GZ-Q100	-40 °C to +125 °C	XSON5	plastic thermal enhanced extremely thin small outline package with side-wettable flanks (SWF); no leads; 5 terminals; body 1.1 × 0.85 × 0.5 mm	SOT8065-1			

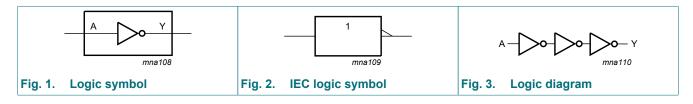
4. Marking

Table 2. Marking

Type number	Marking code[1]
74AUP1G04GV-Q100	p04
74AUP1G04GW-Q100	pC
74AUP1G04GZ-Q100	pC

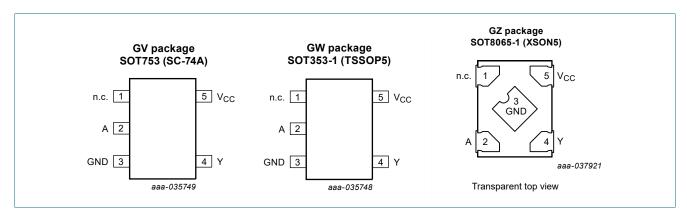
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
n.c.	1	not connected
A	2	data input
GND	3	ground (0 V)
Υ	4	data output
V _{CC}	5	supply voltage

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input	Output
A	Υ
L	Н
Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	active mode [1]	-0.5	V _{CC} + 0.5	V
		power-down mode; V _{CC} = 0 V [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	± 20	mA
I _{CC}	supply current		-	+50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C			
		SOT753 (SC-74A) [2] SOT353-1 (TSSOP5) SOT8065-1 (XSON5)	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SOT753 (SC-74A) package: P_{tot} derates linearly with 3.8 mW/K above 85 °C. For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C. For SOT8065-1 (XSON5) package: P_{tot} derates linearly with 3.2 mW/K above 72 °C.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	active mode	0	V _{CC}	V
		power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V_{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70×V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65×V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 0.8 \text{ V}$	-	-	0.30×V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35×V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	- - - 0.30×V _{CC} 0.35×V _{CC}	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}			- 0.7 V - 0.9 V V V V	
V _{OH}	voltage	$I_O = -20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75×V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	- 0.30×V _{CC} 0.35×V _{CC} 0.7 0.9	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V_{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3×V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	1.9 2.72 2.6	-	0.44	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	± 0.1	μA
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$	-	-	± 0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	± 0.2	μA
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_O = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.8	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70×V _{CC}	- 0.5 µ/4 - 40 µ/4 0.8 - pF 1.7 - pF 1.7 - V V V - 0.30×V _{CC} V - 0.35×V _{CC} V - 0.7 V - 0.9 V V V V V V V V V V V V V V V V V V V	V	
		V _{CC} = 0.9 V to 1.95 V	0.65×V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30×V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35×V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7×V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3×V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	± 0.5	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	± 0.5	μA
ΔI _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	± 0.6	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
Δl _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_0 = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C			'		
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75×V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70×V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25×V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30×V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6×V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH}$ or V_{IL}				
	voltage	I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33×V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	± 0.75	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	± 0.75	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	± 0.75	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = 2	25 °C; C _L = 5 pF					
t _{pd}	propagation delay	A to Y; see <u>Fig. 4</u> [2]				
		V _{CC} = 0.8 V	-	16.0	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.4	5.0	10.3	ns
		V _{CC} = 1.4 V to 1.6 V	1.8	3.6	6.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.5	2.9	5.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.2	2.4	3.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.1	2.1	3.2	ns
T _{amb} = 2	25 °C; C _L = 10 pF					
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]				
		V _{CC} = 0.8 V	-	19.8	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.9	12.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.2	7.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.5	5.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.9	4.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.7	3.8	ns
T _{amb} = 2	25 °C; C _L = 15 pF					
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]				\top
		V _{CC} = 0.8 V	-	23.3	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.7	13.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	4.7	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.0	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.3	5.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.1	4.2	ns
T _{amb} = 2	25 °C; C _L = 30 pF					
t _{pd}	propagation delay	A to Y; see Fig. 4 [2]				
		V _{CC} = 0.8 V	-	33.6	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.4	8.9	16.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	6.3	10.8	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	5.3	9.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.9	4.5	6.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	4.2	5.4	ns

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = 2	5 °C					·
C _{PD}	power dissipation	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]				
	capacitance	V _{CC} = 0.8 V	-	2.5	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.7	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.8	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.0	-	pF

- [1] All typical values are measured at nominal V_{CC} .
- [2] t_{pd} is the same as t_{PLH} and t_{PHL}.
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} × V_{CC}² × f_i × N + ∑(C_L × V_{CC}² × f_o) where:
 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching; $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Table 9. Dynamic characteristics

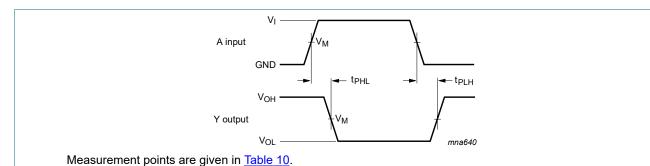
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5

Symbol	Parameter	Conditions	-40 °C	C to +85 °C	-40 °C to	o +125 °C	Unit
			Min	Max	Min	Max	
C _L = 5 p	F				-		
t _{pd}	propagation delay	A to Y; see Fig. 4	[1]				\top
		V _{CC} = 1.1 V to 1.3 V	2.1	11.4	2.1	12.6	ns
		V _{CC} = 1.4 V to 1.6 V	1.6	7.4	1.6	8.2	ns
		V _{CC} = 1.65 V to 1.95 V	1.4	5.9	1.4	6.5	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	4.5	1.1	5.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	3.9	1.0	4.3	ns
C _L = 10	pF						
t _{pd}	propagation delay	A to Y; see Fig. 4	[1]				
		V _{CC} = 1.1 V to 1.3 V	2.6	13.7	2.6	15.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	8.7	2.1	9.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	7.0	1.8	7.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	5.4	1.5	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	4.5	1.4	5.0	ns
C _L = 15	pF						
t _{pd}	propagation delay	A to Y; see Fig. 4	[1]				
		V _{CC} = 1.1 V to 1.3 V	3.0	15.8	3.0	17.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	10.0	2.4	11.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	8.0	2.1	8.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	6.1	1.8	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	5.0	1.8	5.5	ns

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
C _L = 30	pF						·
t _{pd}	propagation delay	A to Y; see <u>Fig. 4</u> [1]					
		V _{CC} = 1.1 V to 1.3 V	4.0	19.0	4.0	20.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.2	12.9	3.2	14.2	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	10.5	2.9	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	7.6	2.6	8.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	6.2	2.6	6.9	ns

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

11.1. Waveform and test circuit

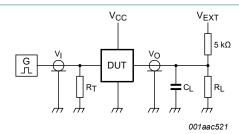


Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. The data input (A) to output (Y) propagation delays

Table 10. Measurement points

Supply voltage	Output	Input			
V _{CC}	V _M	V _M	VI	$t_r = t_f$	
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 5. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

^[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12. Package outline

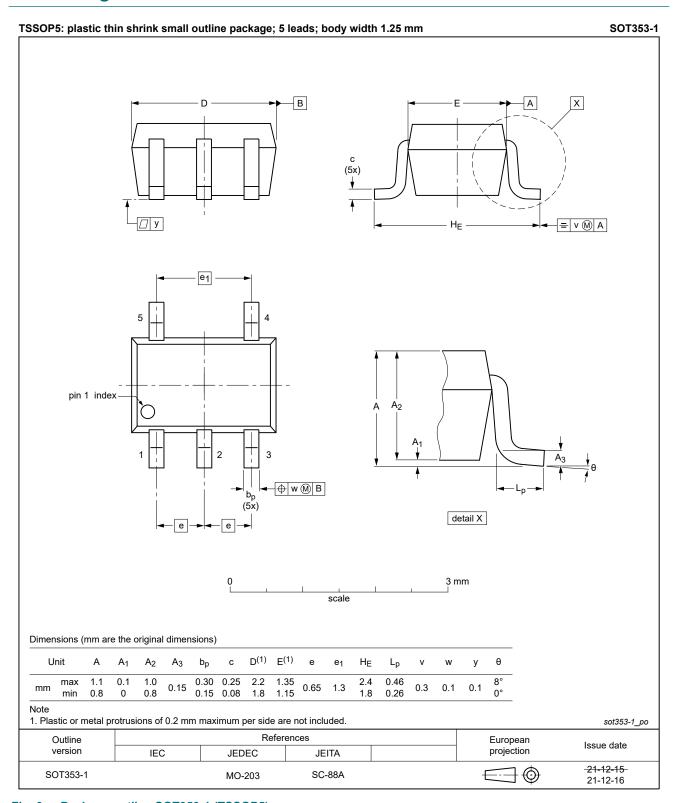


Fig. 6. Package outline SOT353-1 (TSSOP5)

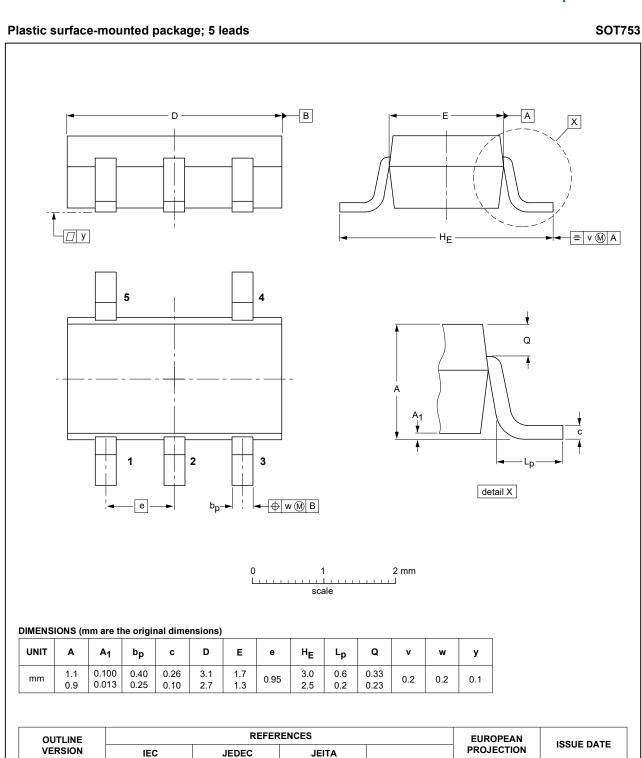


Fig. 7. Package outline SOT753 (SC-74A)

SOT753

SC-74A

02-04-16

06-03-16

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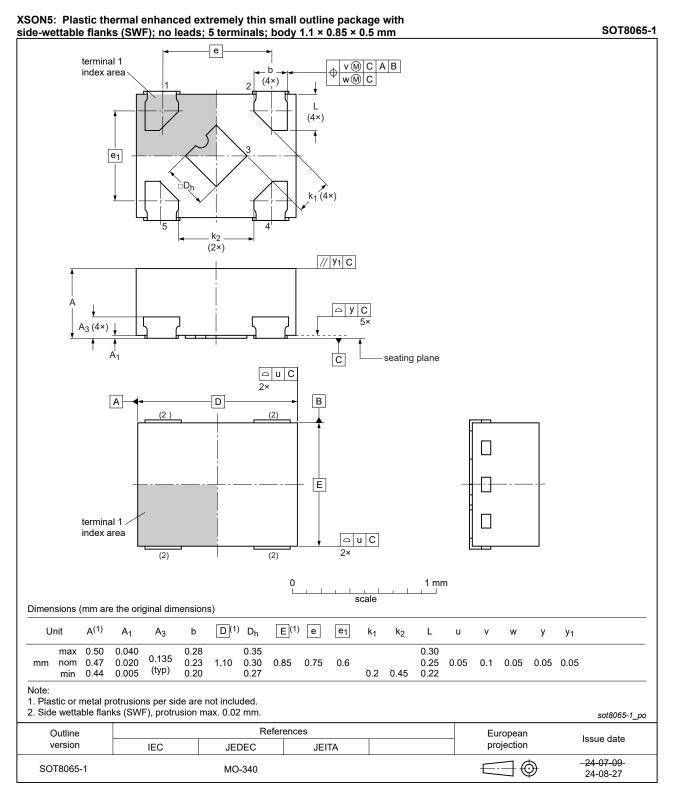


Fig. 8. Package outline SOT8065-1 (XSON5)

13. Abbreviations

Table 12. Abbreviations

Acronym	Description		
ANSI	American National Standards Institute		
CDM	Charged Device Model		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
ESDA	ElectroStatic Discharge Association		
НВМ	Human Body Model		
JEDEC	Joint Electron Device Engineering Council		

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1G04_Q100 v.5	20240920	Product data sheet	-	74AUP1G04_Q100 v.4.1		
Modifications:	Type number 74AUP1G04GZ-Q100 (SOT8065-1/XSON5) added.					
74AUP1G04_Q100 v.4.1	20230711	Product data sheet	-	74AUP1G04_Q100 v.3		
Modifications:	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.					
74AUP1G04_Q100 v.3	20220113	Product data sheet	-	74AUP1G04_Q100 v.2		
Modifications:	 <u>Section 1</u> and <u>Section 2</u> updated. <u>Fig. 6</u>: Package outline drawing for SOT353-1(TSSOP5) has changed. 					
74AUP1G04_Q100 v.2	20210430	Product data sheet	-	74AUP1G04_Q100 v.1		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Table 5: Derating values for P_{tot} total power dissipation have been updated. 					
74AUP1G04_Q100 v.1	20131118	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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